

Official**IN THE CLAIMS****FAX RECEIVED****JUN 15 1999****GROUP 1700**

164. (Added) A method according to claim 129 wherein said composition comprises a substantially layered perovskite crystal structure.

165. (Added) A method according to claim 130 wherein said superconducting transistor metal oxide comprises a substantially layered perovskite crystal structure.

166. (Added) A method according to claim 131 wherein said superconducting copper oxide comprises a substantially layered perovskite crystal structure.

167. (Added) A method according to claim 132 wherein said superconducting oxide composition comprises a substantially layered perovskite crystal structure.

168. (Added) A method according to claim 133 wherein said superconducting oxide composition comprises a substantially layered perovskite crystal structure.

169. (Added) A method according to claim 134 wherein said transistor metal oxide comprises a substantially layered perovskite crystal structure.
170. (Added) A method according to claim 135 wherein said copper oxide comprises a substantially layered perovskite crystal structure.
171. (Added) A method according to claim 136 wherein said composition comprises a substantially layered perovskite crystal structure.
172. (Added) A method according to claim 137 wherein said composition of matter comprises a substantially layered perovskite crystal structure.
173. (Added) A method according to claim 138 wherein said composition of matter comprises substantially layered perovskite crystal structure.
174. (Added) A method according to claim 139 wherein said composition of matter comprises a substantially layered perovskite crystal structure.
175. (Added) A method according to claim 140 wherein said composition of matter comprises substantially layered perovskite crystal structure.